



# PUMD9-Q

NPN/PNP resistor-equipped transistors;

R1 = 10 k $\Omega$ , R2 = 47 k $\Omega$

25 June 2021

Product data sheet

## 1. General description

NPN/PNP double Resistor-Equipped Transistors (RET) in a very small SOT363 (SC-88) Surface-Mounted Device (SMD) plastic package.

## 2. Features and benefits

- 100 mA output current capability
- Built-in bias resistors
- Simplifies circuit design
- Reduces component count
- Reduces pick and place costs
- Qualified according to AEC-Q101 and recommended for use in automotive applications

## 3. Applications

- Low current peripheral driver
- Control of IC inputs
- Replacement of general purpose transistors in digital applications

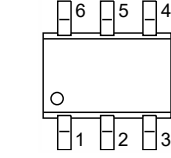
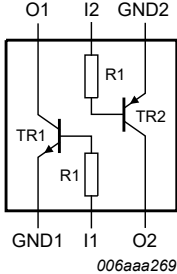
## 4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
<b>Per transistor, for the PNP transistor with negative polarity</b>						
V <sub>CEO</sub>	collector-emitter voltage	open base	-	-	50	V
I <sub>O</sub>	output current		-	-	100	mA
R1	bias resistor 1		7	10	13	k $\Omega$
R2/R1	bias resistor ratio		3.7	4.7	5.7	

## 5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	GND1	GND (emitter) TR1	 <p><b>TSSOP6 (SOT363)</b></p>	
2	I1	input (base) TR1		
3	O2	output (collector) TR2		
4	GND2	GND (emitter) TR2		
5	I2	input (base) TR2		
6	O1	output (collector) TR1		

## 6. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
PUMD9-Q	TSSOP6	plastic, surface-mounted package; 6 leads; 0.65 mm pitch; 2.1 mm x 1.25 mm x 0.95 mm body	SOT363

## 7. Marking

Table 4. Marking codes

Type number	Marking code[1]
PUMD9-Q	D%9

[1] % = placeholder for manufacturing site code

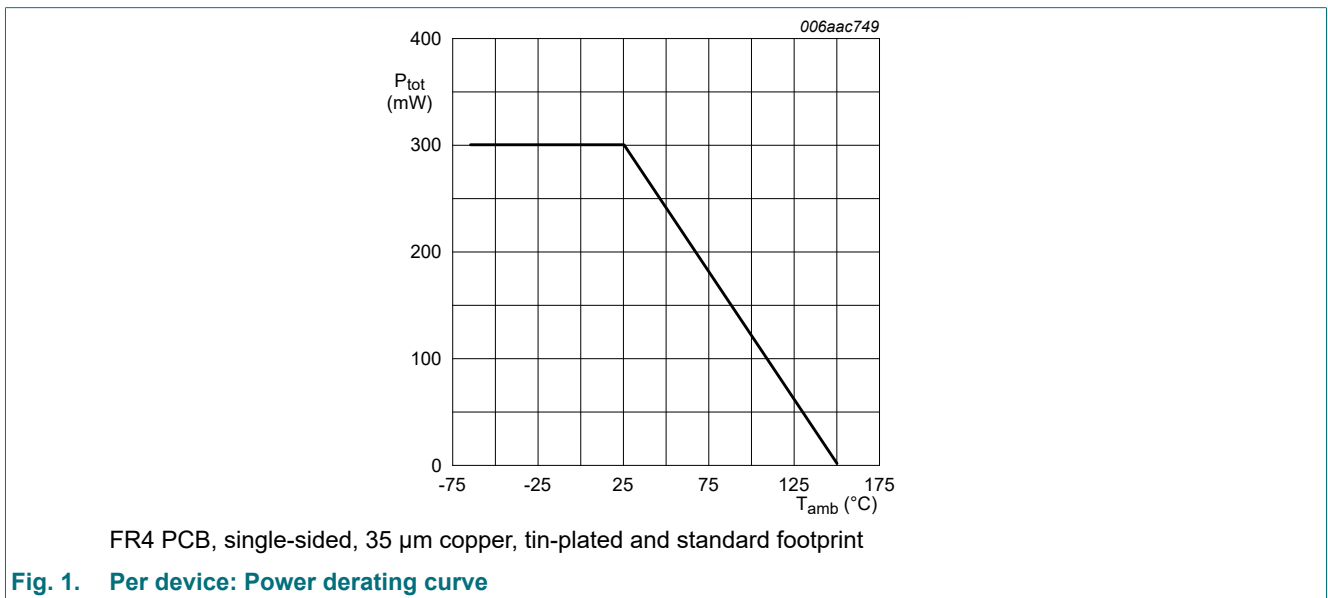
## 8. Limiting values

**Table 5. Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit	
<b>Per transistor, for the PNP transistor with negative polarity</b>						
V <sub>CBO</sub>	collector-base voltage	open emitter	-	50	V	
V <sub>CEO</sub>	collector-emitter voltage	open base	-	50	V	
V <sub>EBO</sub>	emitter-base voltage	open collector	-	6	V	
V <sub>I</sub>	input voltage	input voltage TR1	-	40	V	
			-	-6	V	
		input voltage TR2	-	6	V	
			-	-40	V	
I <sub>O</sub>	output current		-	100	mA	
I <sub>CM</sub>	peak collector current	t <sub>p</sub> ≤ 1 ms; single pulse	-	100	mA	
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C	[1]	-	200	mW
<b>Per device</b>						
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C	[1]	-	300	mW
T <sub>j</sub>	junction temperature		-	150	°C	
T <sub>amb</sub>	ambient temperature		-65	150	°C	
T <sub>stg</sub>	storage temperature		-65	150	°C	

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided, 35 μm copper, tin-plated and standard footprint.

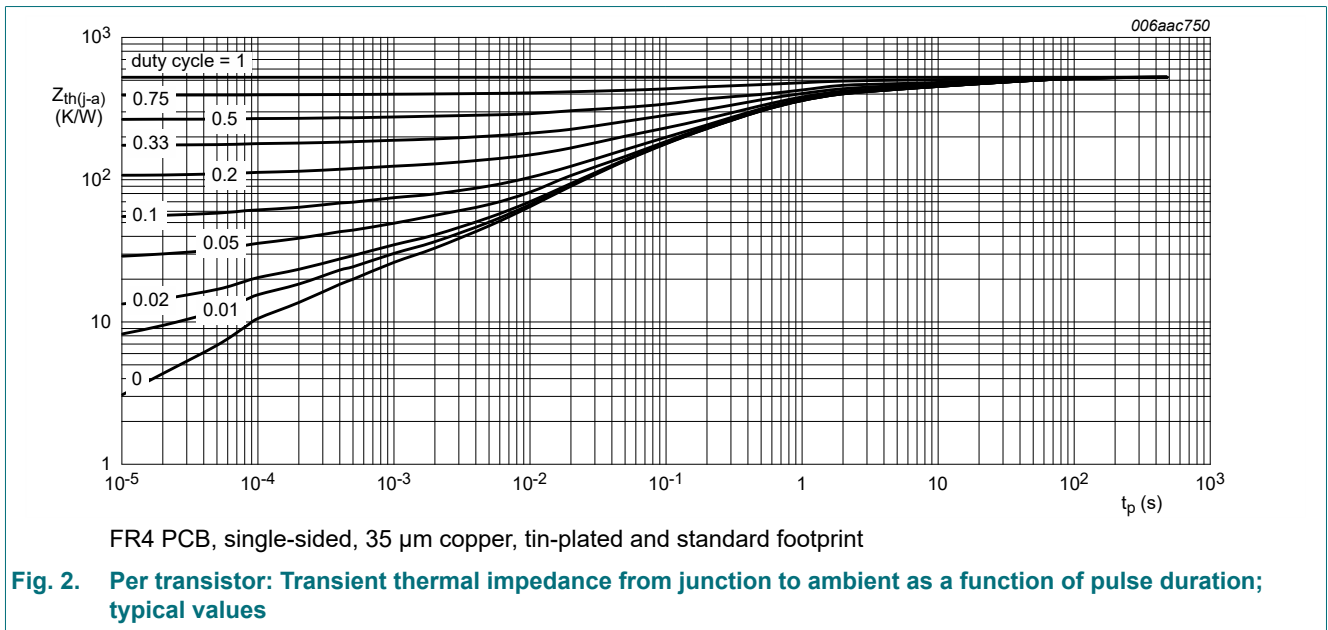


## 9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
<b>Per transistor</b>							
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	-	625	K/W
<b>Per device</b>							
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	-	417	K/W

[1] Device mounted on an FR4 PCB, single-sided, 35 μm copper, tin-plated and standard footprint.



## 10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
<b>Per transistor, for the PNP transistor with negative polarity</b>						
$V_{(BR)CBO}$	collector-base breakdown voltage	$I_C = 100 \mu\text{A}$ ; $I_E = 0 \text{ A}$ ; $T_{\text{amb}} = 25 \text{ }^\circ\text{C}$	50	-	-	V
$V_{(BR)CEO}$	collector-emitter breakdown voltage	$I_C = 2 \text{ mA}$ ; $I_B = 0 \text{ A}$ ; $T_{\text{amb}} = 25 \text{ }^\circ\text{C}$	50	-	-	V
$V_{(BR)EBO}$	emitter-base breakdown voltage	$I_C = 0 \text{ A}$ ; $I_E = 100 \mu\text{A}$ ; $T_{\text{amb}} = 25 \text{ }^\circ\text{C}$	6	-	-	V
$I_{CBO}$	collector-base cut-off current	$V_{CB} = 50 \text{ V}$ ; $I_E = 0 \text{ A}$ ; $T_{\text{amb}} = 25 \text{ }^\circ\text{C}$	-	-	100	nA
$I_{CEO}$	collector-emitter cut-off current	$V_{CE} = 30 \text{ V}$ ; $I_B = 0 \text{ A}$ ; $T_{\text{amb}} = 25 \text{ }^\circ\text{C}$	-	-	1	$\mu\text{A}$
		$V_{CE} = 30 \text{ V}$ ; $I_B = 0 \text{ A}$ ; $T_J = 150 \text{ }^\circ\text{C}$	-	-	5	$\mu\text{A}$
$I_{EBO}$	emitter-base cut-off current	$V_{EB} = 5 \text{ V}$ ; $I_C = 0 \text{ mA}$ ; $T_{\text{amb}} = 25 \text{ }^\circ\text{C}$	-	-	150	$\mu\text{A}$
$h_{FE}$	DC current gain	$V_{CE} = 5 \text{ V}$ ; $I_C = 5 \text{ mA}$ ; $T_{\text{amb}} = 25 \text{ }^\circ\text{C}$	100	-	-	
$V_{CEsat}$	collector-emitter saturation voltage	$I_C = 5 \text{ mA}$ ; $I_B = 0.25 \text{ mA}$ ; $T_{\text{amb}} = 25 \text{ }^\circ\text{C}$	-	-	100	mV
$V_{I(off)}$	off-state input voltage	$V_{CE} = 5 \text{ V}$ ; $I_C = 100 \mu\text{A}$ ; $T_{\text{amb}} = 25 \text{ }^\circ\text{C}$	-	0.7	0.5	V
$V_{I(on)}$	on-state input voltage	$V_{CE} = 0.3 \text{ V}$ ; $I_C = 1 \text{ mA}$ ; $T_{\text{amb}} = 25 \text{ }^\circ\text{C}$	1.4	0.8	-	V
R1	bias resistor 1		7	10	13	kΩ
R2/R1	bias resistor ratio		3.7	4.7	5.7	
<b>TR1 (NPN)</b>						
$C_c$	collector capacitance	$V_{CB} = 10 \text{ V}$ ; $I_E = 0 \text{ A}$ ; $i_e = 0 \text{ A}$ ; $f = 1 \text{ MHz}$ ; $T_{\text{amb}} = 25 \text{ }^\circ\text{C}$	-	-	2.5	pF
$f_T$	transition frequency	$V_{CE} = 5 \text{ V}$ ; $I_C = 10 \text{ mA}$ ; $f = 100 \text{ MHz}$ ; $T_{\text{amb}} = 25 \text{ }^\circ\text{C}$	[1]	230	-	MHz
<b>TR2 (PNP)</b>						
$C_c$	collector capacitance	$V_{CB} = 10 \text{ V}$ ; $I_E = 0 \text{ A}$ ; $i_e = 0 \text{ A}$ ; $f = 1 \text{ MHz}$ ; $T_{\text{amb}} = 25 \text{ }^\circ\text{C}$	-	-	3	pF
$f_T$	transition frequency	$V_{CE} = 5 \text{ V}$ ; $I_C = 10 \text{ mA}$ ; $f = 100 \text{ MHz}$ ; $T_{\text{amb}} = 25 \text{ }^\circ\text{C}$	[1]	180	-	MHz

[1] Characteristics of built-in transistor

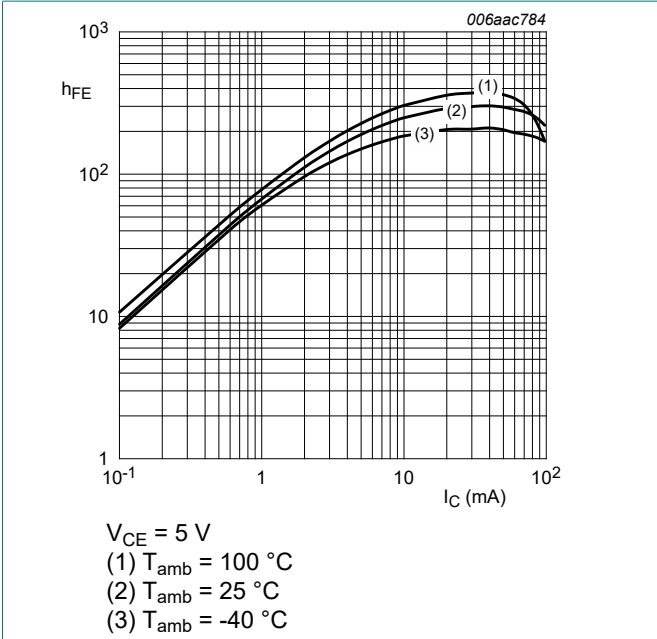


Fig. 3. TR1 (NPN): DC current gain as a function of collector current; typical values

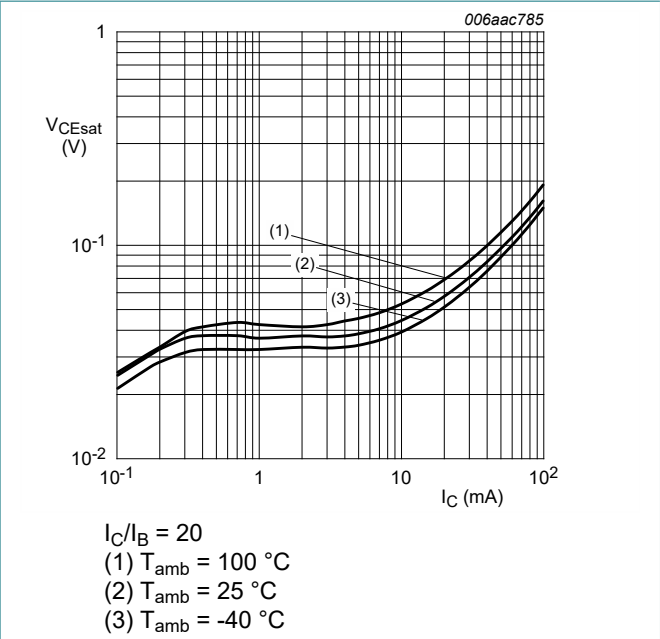


Fig. 4. TR1 (NPN): Collector-emitter saturation voltage as a function of collector current; typical values

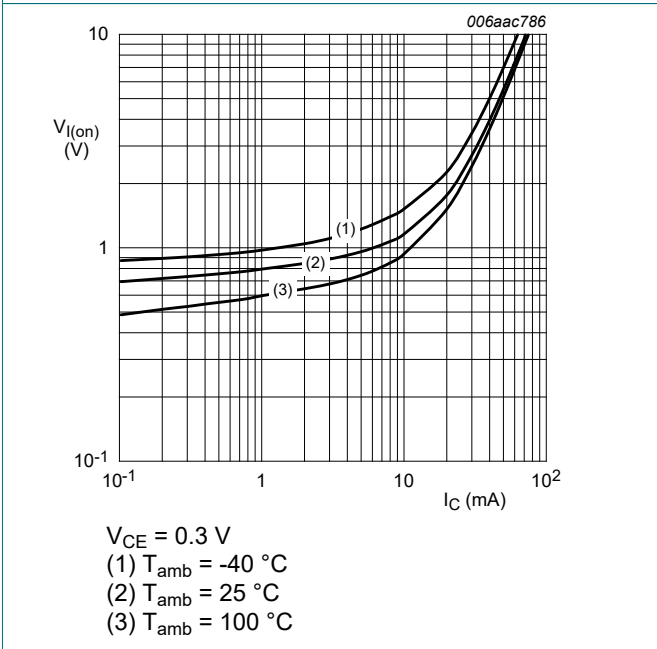


Fig. 5. TR1 (NPN): On-state input voltage as a function of collector current; typical values

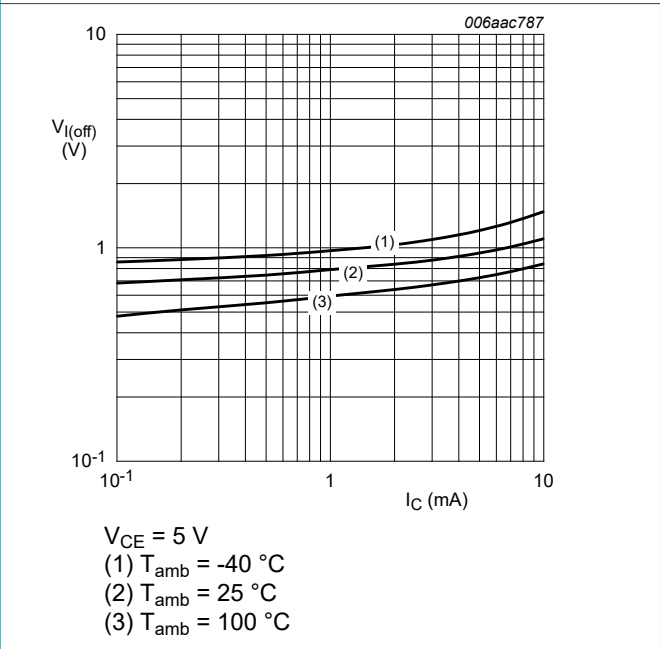
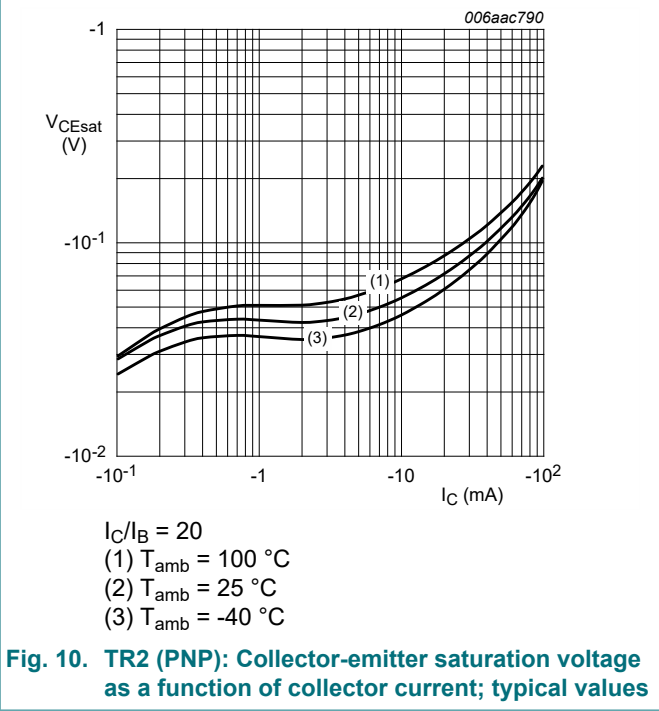
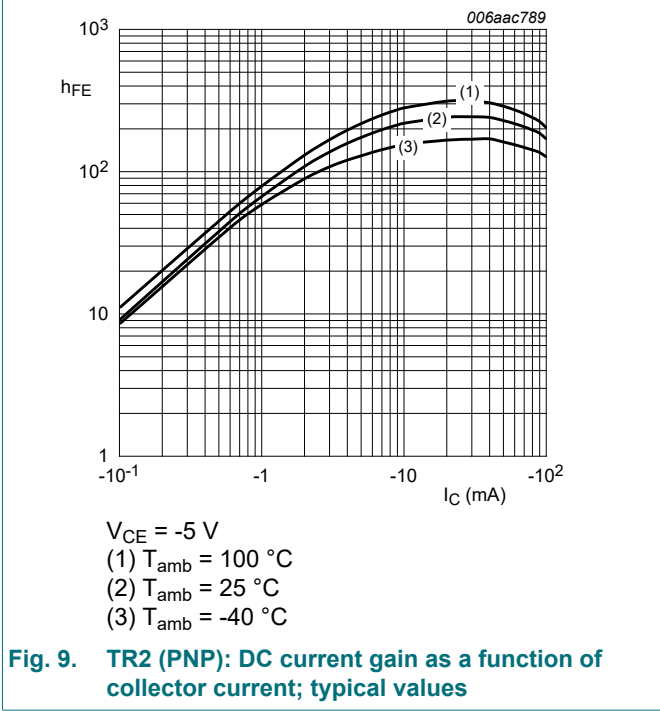
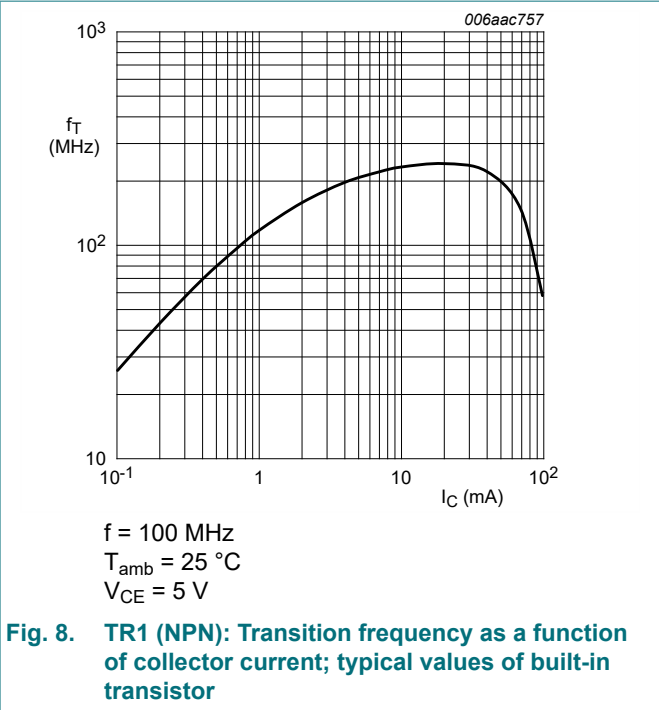
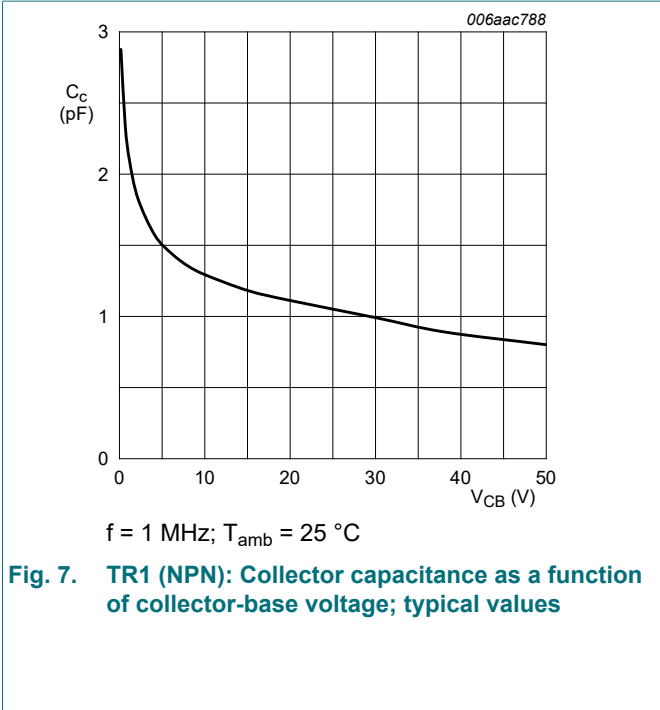


Fig. 6. TR1 (NPN): Off-state input voltage as a function of collector current; typical values



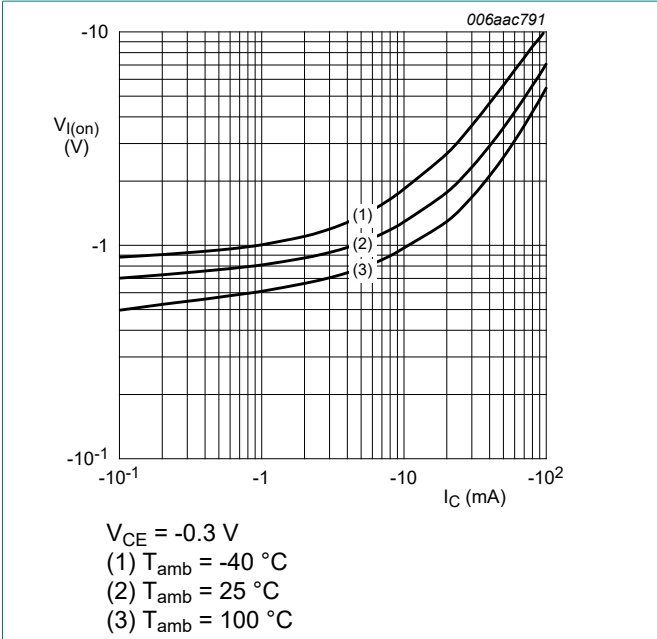


Fig. 11. TR2 (PNP): On-state input voltage as a function of collector current; typical values

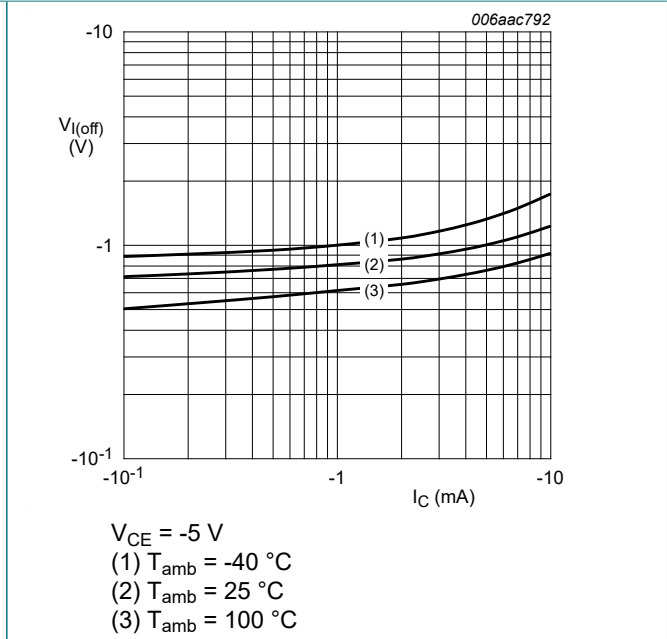


Fig. 12. TR2 (PNP): Off-state input voltage as a function of collector current; typical values

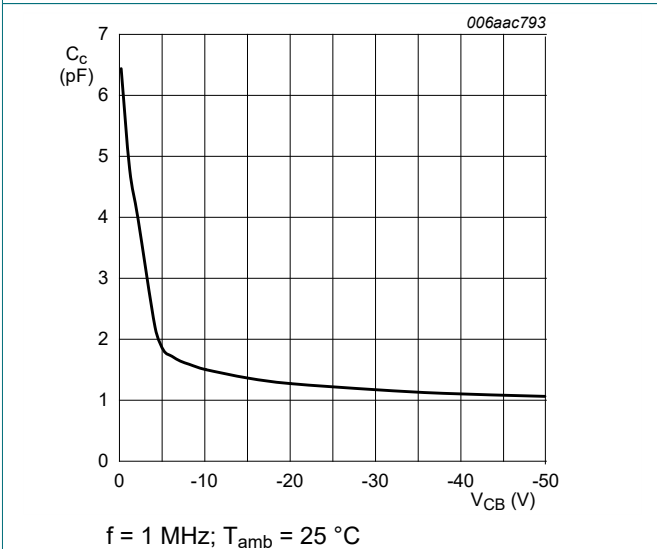


Fig. 13. TR2 (PNP): Collector capacitance as a function of collector-base voltage; typical values

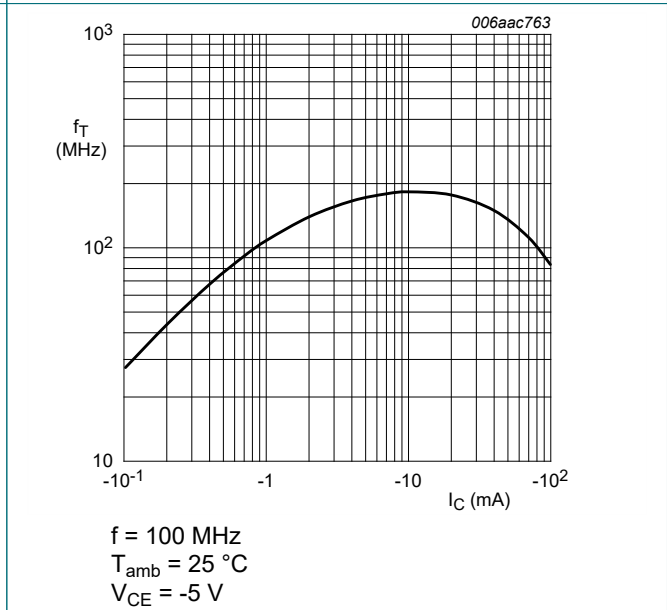


Fig. 14. TR2 (PNP): Transition frequency as a function of collector current; typical values of built-in transistor

## 11. Test information

### Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

## 12. Package outline

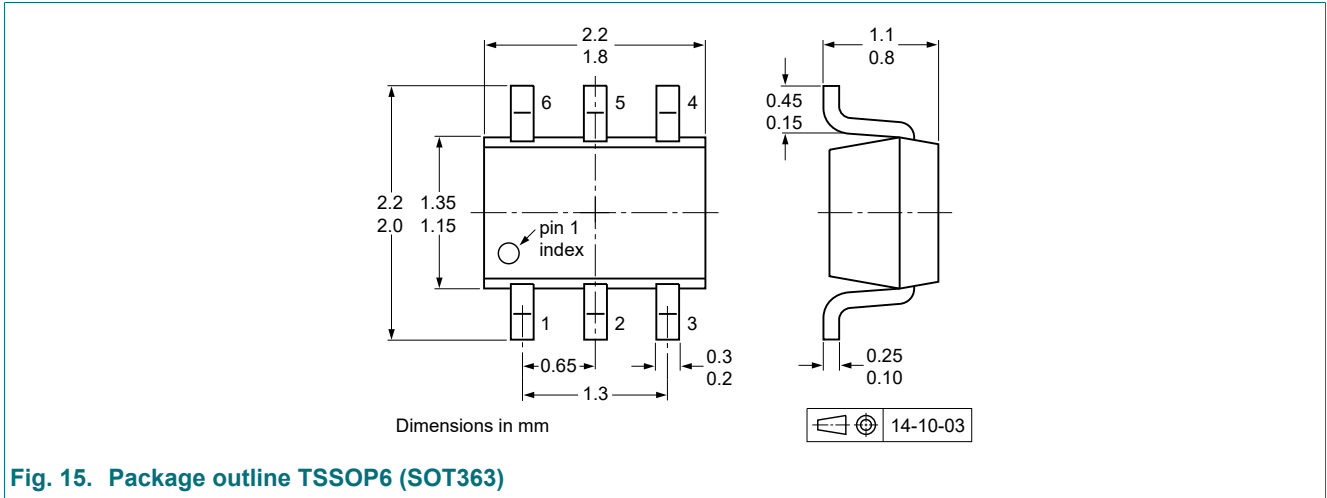


Fig. 15. Package outline TSSOP6 (SOT363)

### 13. Soldering

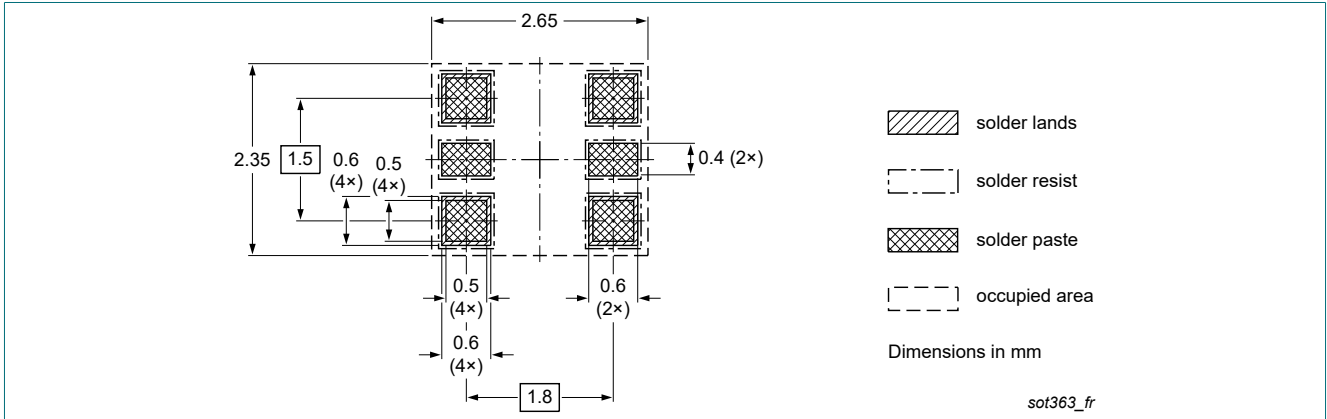


Fig. 16. Reflow soldering footprint for TSSOP6 (SOT363)

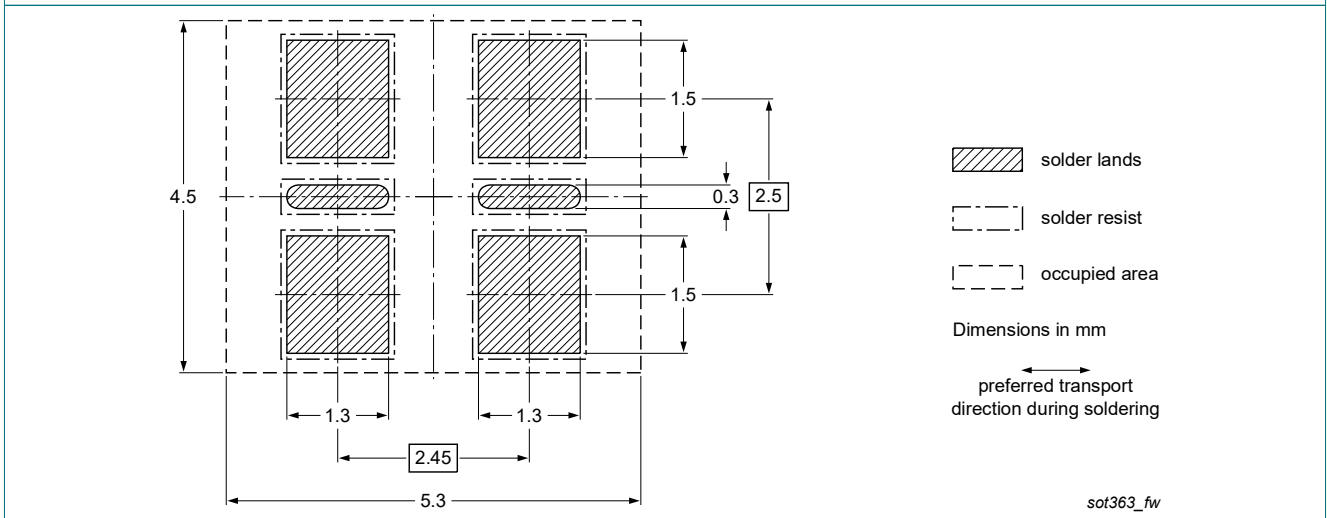


Fig. 17. Wave soldering footprint for TSSOP6 (SOT363)

## 14. Revision history

Table 8. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
PUMD9-Q v.1	20210625	Product data sheet	-	-

## 15. Legal information

### Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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